



MMBTA13LT3G Information



For Reference Only

Part Number MMBTA13LT3G Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN DARL 30V 0.3A SOT23

Package TO-236-3, SC-59, SOT-23-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









MMBTA13LT3G Specifications

Manufacturer Part Number	MMBTA13LT3G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	NPN - Darlington
Current - Collector (Ic) (Max)	300mA
Voltage - Collector Emitter Breakdown (Max)	30V
Vce Saturation (Max) @ Ib, Ic	1.5V @ 100μA, 100mA
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	10000 @ 100mA, 5V
Power - Max	225mW
Frequency - Transition	125MHz
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	SOT-23-3 (TO-236)
	Report errors?

MMBTA13LT3G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MMBTA13LT3G Payment Methods





















MMBTA13LT3G Shipping Methods













If you have any question about MMBTA13LT3G, please do not hesitate to contact us!

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